

40V PNP SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Complementary NPN Type: MMBT3904
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

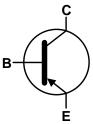
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads,
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)

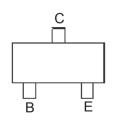








Device Symbol



Top View Pin-Out

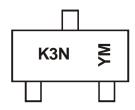
Ordering Information (Notes 4 & 5)

Ī	Product	Status	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	MMBT3906-7-F	Active	AEC-Q101	K3N	7	8	3,000
	MMBT3906Q-7-F	Active	Automotive	K3N	7	8	3,000
	MMBT3906-13-F	Active	AEC-Q101	K3N	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K3N = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2015	20	016	2017	2	018	2019		2020	2021		2022
Code	С		D	Е		F	G		Н			J
Month	т.			1 .	T			A	0	0-1	Niere	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-6.0	V
Collector Current	Ic	-200	mA
Peak Collector Current	I _{CM}	-200	mA
Peak Base Current	I _{BM}	-100	mA

Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	C	310	mW	
Fower Dissipation	(Note 7)	P_{D}	350	IIIVV	
Thermal Desistance Junction to Ambient	(Note 6)		403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	357	°C/VV	
Thermal Resistance, Junction to Leads (Note 8)		R _{θJL}	350	°C/W	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 9)

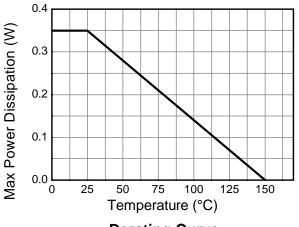
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

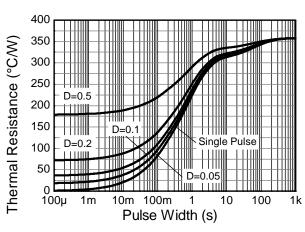
Notes:

- 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as note (6), except the device is mounted on 15 mm x 15mm 1oz copper. 8. Thermal resistance from junction to solder-point (at the end of the leads).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



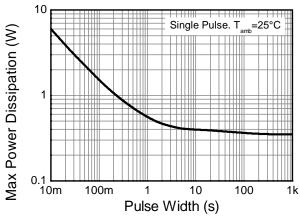
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



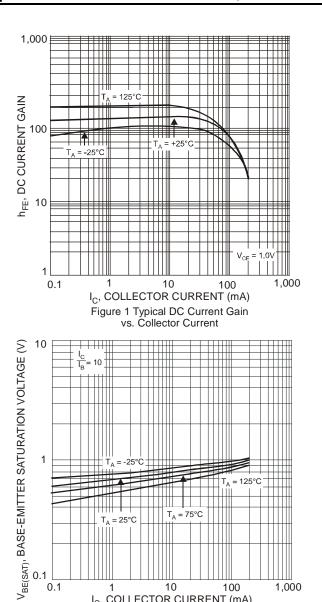
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS			•	•	
Collector-Base Breakdown Voltage	BV _{CBO}	-40	_	V	$I_C = -100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 10)	BV_{CEO}	-40	_	V	$I_C = -10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV_{EBO}	-6.0	_	V	$I_E = -100 \mu A, I_C = 0$
Collector Cutoff Current	1		-50	nA	$V_{CE} = -30V, V_{BE} = 3.0V$
Collector Cutoff Current	ICEV	_	-50	nA	$V_{CE} = -30V, V_{BE} = -0.25V$
Emitter-Base Cutoff Current	I _{EBO}	_	-50	nA	$V_{EB} = -5V$
ON CHARACTERISTICS (Note 10)					
		60	_		$I_C = -100 \mu A, V_{CE} = -1.0 V$
		80	_		$I_C = -1.0 \text{mA}, V_{CE} = -1.0 \text{V}$
DC Current Gain	h_{FE}	100	300	_	$I_C = -10 \text{mA}, V_{CE} = -1.0 \text{V}$
		60			$I_C = -50 \text{mA}, V_{CE} = -1.0 \text{V}$
		30	_		$I_C = -100 \text{mA}, V_{CE} = -1.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	-0.25	V	$I_C = -10mA$, $I_B = -1.0mA$
Composer Emmer Catalianon voltage	V CL(Sat)		-0.40	•	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(sat)}	-0.65	-0.85	V	$I_C = -10 \text{mA}, I_B = -1.0 \text{mA}$
ŭ	V DE(Sat)	_	-0.95	•	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS	1	1	1	ı	
Output Capacitance	C _{obo}		4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	Cibo		10	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_{C} = 0$
Input Impedance	h _{ie}	2.0	12	kΩ	
Voltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴	$V_{CE} = 10V, I_{C} = 1.0mA,$
Small Signal Current Gain	h _{fe}	100	400	_	f = 1.0kHz
Output Admittance	h _{oe}	3.0	60	μS	
Current Gain-Bandwidth Product	f⊤	250	_	MHz	$V_{CE} = -20V, I_{C} = -10mA,$ f = 100MHz
Noise Figure	NF		4.0	dB	$V_{CE} = -5.0V$, $I_{C} = -100\mu A$, $R_{S} = 1.0k\Omega$, $f = 1.0kHz$
SWITCHING CHARACTERISTICS					
Delay Time	t _d	_	35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
Rise Time	t _r	_	35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$
Storage Time	ts	_	225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
Fall Time	t _f		75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



10 I_C, COLLECTOR CURRENT (mA) Figure 3 Typical Base-Emitter Saturation Voltage vs. Collector Current

100

1,000

0.1

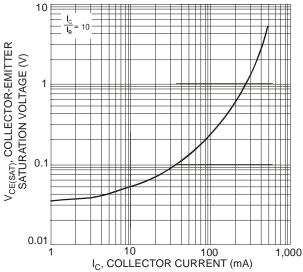


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

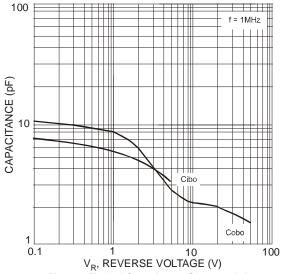
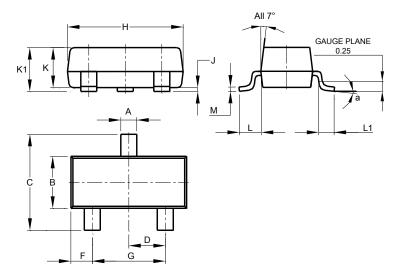


Figure 4 Typical Capacitance Characteristics



Package Outline Dimensions

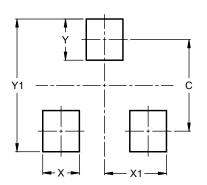
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	K1 0.903		1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	29



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